Temperature Switch IC with Hysteresis Monolithic IC MM3688

Outline

This IC is a temperature switch IC that changes the IC output level from Low to High when the temperature around the IC reaches the detection temperature. With the hysteresis function, IC output level returns to Low when the ambient temperature drops to the hysteresis temperature selected after detection. Detection temperature TDET can be selected in 1.0° C steps between the range of 60 to 90° C with rank expansion, with detection temperature accuracy of $\pm 2.0^{\circ}$ C.

Current consumption is less than 1/10 of our existing products at 0.12μ A typ.

Features

(Except where noted otherwise Topr=+25°C)

- 1. Detection temperature range.
- 2. Low current consumption.
- 3. High Temperature accuracy.
- 4. Low power supply operation range.
- 5. Operating temperature range.
- 6. Hysteresis temperature

+60~+90°C 0.12μA typ. ±2.0°C 1.6~5.0V -40~+125°C 5°C steps (10, 15, 20, 25°C)

Package

PLP-4A

Applications

- 1. Smartphones, Cellular phones
- 2. Flat TVs
- 3. Game equipments
- 4. Tablets, PCs
- 5. System thermal monitor
- 6. OA equipments

Any products mentioned in this catalog are subject to any modification in their appearance and others for improvements without prior notification.
 The details listed here are not a guarantee of the individual products at the time of ordering. When using the products, you will be asked to check their specifications

Model Name

N	I M	3	6	8	8	× 1	×	2	R 3	R 4	E	
		1							2			
Hysteresis Temperature (THYS)					Detecitng Temperature (TDET)							
В	THYS=10°C			6	0		TD	ET=60	°C			
С	THYS=15°C						TDET is 1.0°C stops					
D		TH	IYS=20)°C		٦ '		TDET is 1.0°C steps			c steps	
E	THYS=25°C			9	0		TD	ET=90	°C			

	3	4			
	Package	Packing Specifications			
R	PLP-4A	R	R HOUSING (PLP-4A Standard)		
		L	L HOUSING		

Block Diagram



Pin Assignment



Note1 : The tab on the center of the bottom face is connected to the IC substrate inside the package. To use the device, it should be shorted to GND or OPEN.

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Pin No.	Pin Name	Function	Internal Equivalent Circuit
1	DET	Temp. Detect Output Pin	
2	GND	Ground pin	
3	REF(Note2)	REF pin	
4	VDD	Power supply pin	

Pin Description

Note2 : REF pin is connected with the internal circuit because it use for testing. When REF pin is connected with resistance and capacity, this product produce improper operating signals. Please set REF pin to the open state.

Absolute Maximum Ratings

Item	Symbol	Ratings	Units	
Supply voltage	VDD	-0.3~6.0	V	
Terminal voltage	DETmax	-0.3~6.0	V	
Junction temperature	Тјмах	150	°C	
Storage temperature	Tstg	-55~125	°C	
Power dissipation	Pd	400 (Note3)	mW	

Note3 : With PC Board of glass epoxy ($60 \times 40 \times 1.6^{t}$ mm)

Recommended Operating Conditions

Item	Symbol	Ratings	Units	
Operating ambient temperature	Topr	-40~125	°C	
Operating supply voltage	V_{op}	1.6~5.0	V	

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Item	Symbol	Measurement conditions	Min.	Тур.	Max.	Units
Operating supply voltage	Vop	TDET=60~90°C	1.6	1.8	5.0	V
Detecting temperature accuracy (Note4)	TDETAC		-2.0		2.0	°C
		THYS=10°C		10.0		Units V °C °C μΑ mA μΑ mA
	Thys	THYS=15°C		15.0		
Hysteresis temperature		THYS=20°C		20.0		
		THYS=25°C		25.0		
Supply current	Idd			0.12	0.30	μA
DET sink current	Idetl	VDET=0.4V, VDET=Low Level	4	12		mA
DET leak current	ILEAK	VDET=5.0V, VDET=High Level			0.1	μA
Interval timer	tint			50		ms
VDD start-up response time	tvsr	RPULL-UP=1M		100	500	μs

Electrical Characteristics (Except where noted otherwise Ta=25°C, VDD=1.8V)

Note4 : Detection temperature can be selected in 1.0°C steps (60~90°C).

Measuring Circuit

1. Supply Current



2. DET Sink Current State of DET output Low level



3. Start-up Response



4. Detecting Temperature



H : State of DET output Low level H : State of DET output High level Ta = $+40 \rightarrow 100^{\circ}$ C

5. Hysteresis Temperature



H : State of DET output Low level Ta = $+100 \rightarrow 40^{\circ}C$

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Timing Chart





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Typical Application Circuit



- \cdot We shall not be liable for any trouble or damage caused by using this circuit.
- In the event a problem which may affect industrial property or any other rights of us or a third party is encountered during the use of information described in these circuit, Mitsumi Electric Co., Ltd. shall not be liable for any such problem, nor grant a license therefore.

Typical Characteristics (Except where noted otherwise Ta=25°C, VDD=1.8V)

Ambient temperature - Supply current











Supply voltage - Hysteresis temperature









Start-up response (Ta≧TDET)



t (5ms/div)



